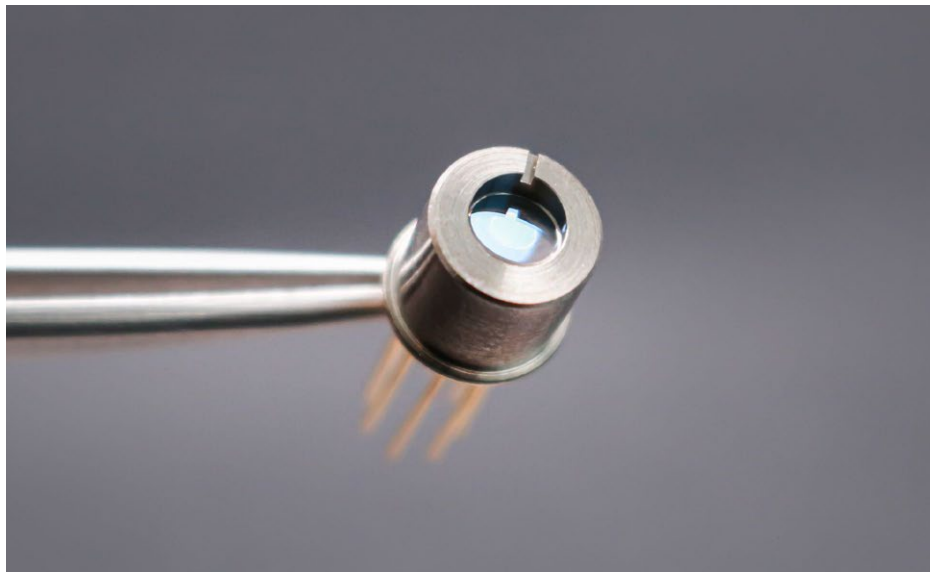


2108nm DFB Laser diode for N₂O Gas monitoring (TO39 Package)



Description:

The PL-DFB-2108-A-A81 2108nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed TO39 package with TEC and PD Built in.

Features:

- Narrow Linewidth < 2MHz
- Excellent wavelength control and stability
- Mode-Hop free tuning
- Excellent reliability
- Customer specific wavelengths available

Application:

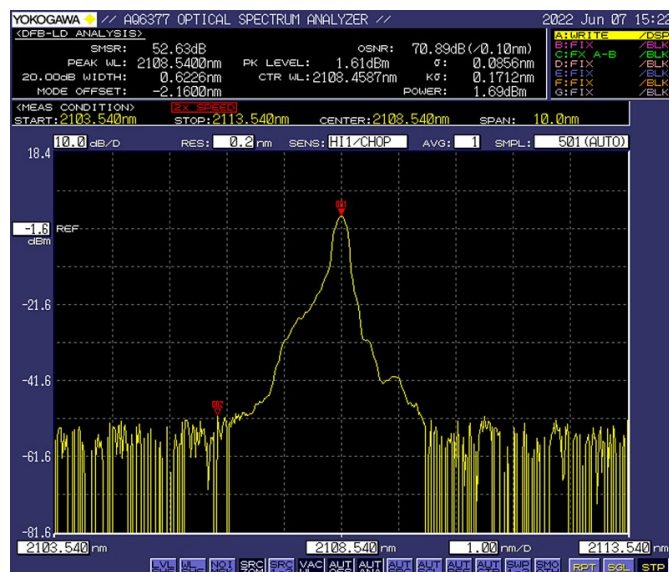
- Tunable diode laser absorption spectroscopy
- N₂O Monitoring

Laser Specifications:

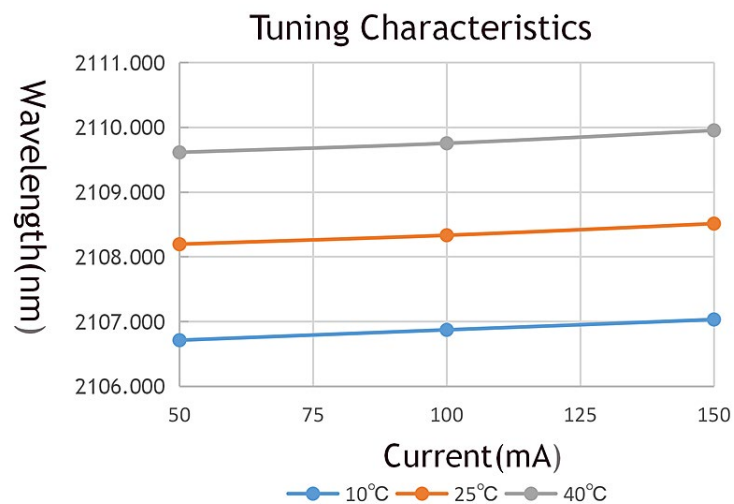
Tsub=25°C, CW bias unless stated otherwise

Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	λ	2059	2060	2061	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	I _{th}		20	30	mA
Operating Current	I _{op}		80	120	mA
Chip output Power	P _f	2	3	5	mW
Quantum Efficiency	η	0.08	0.12		mW/mA
Current Tuning Coefficient	$\Delta\lambda/\Delta I$		0.015		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda/\Delta T$		0.12		nm/K
Forward Voltage	V _f		1.3	2	V
Thermistor Resistance	R _T	9.5	10	10.5	K Ω
Thermistor Temp. Coefficient			-4.4		%/°C

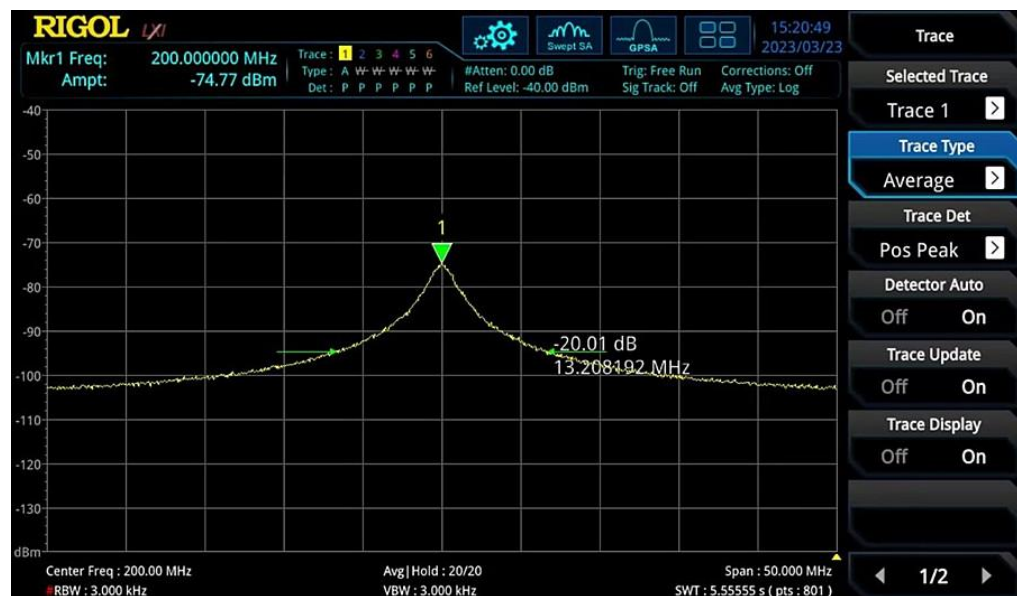
Spectrum:



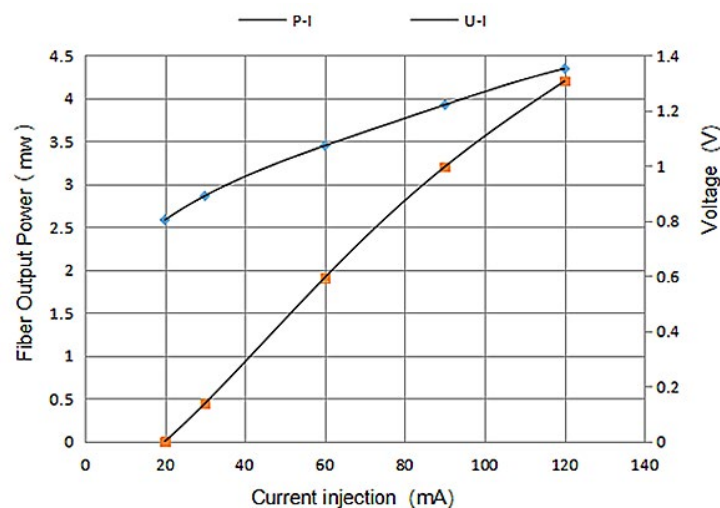
Tuning Characteristics:



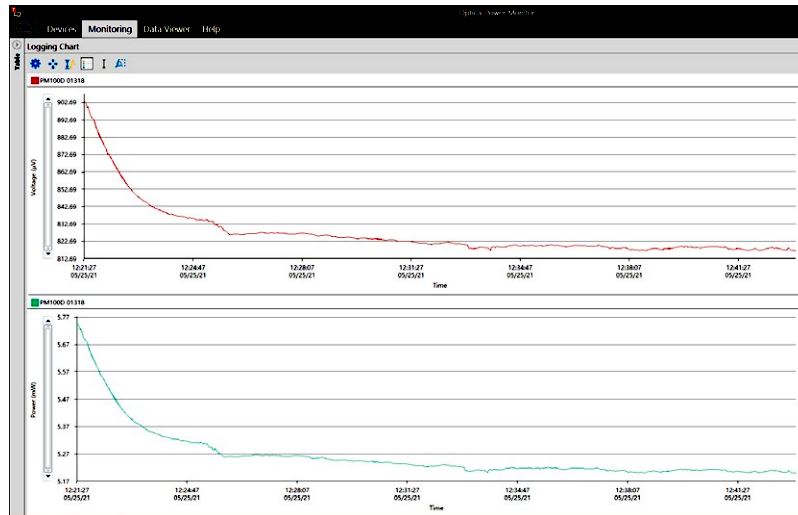
DFB Linewidth Testing Result:



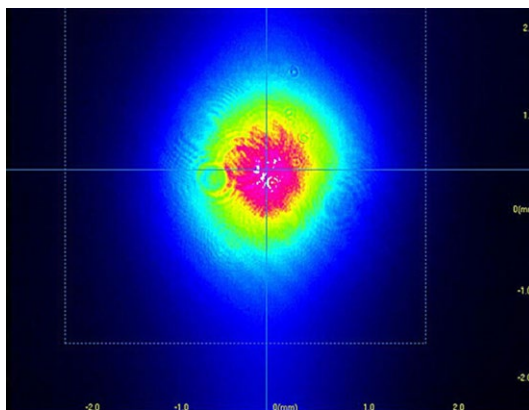
L-I Curve:



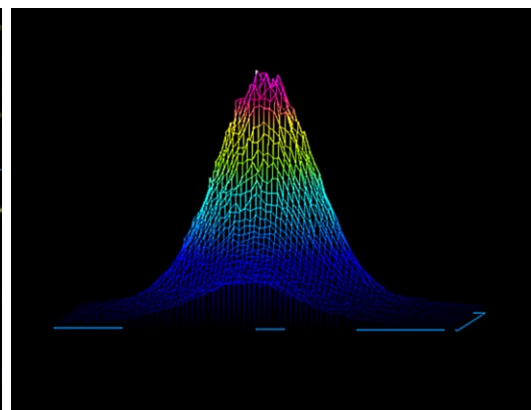
Power Stability:



Beam Quality:

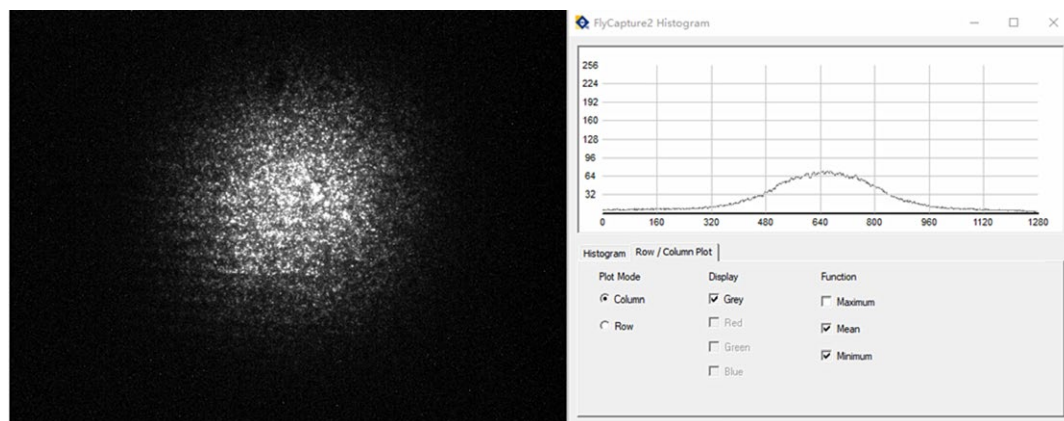


2D

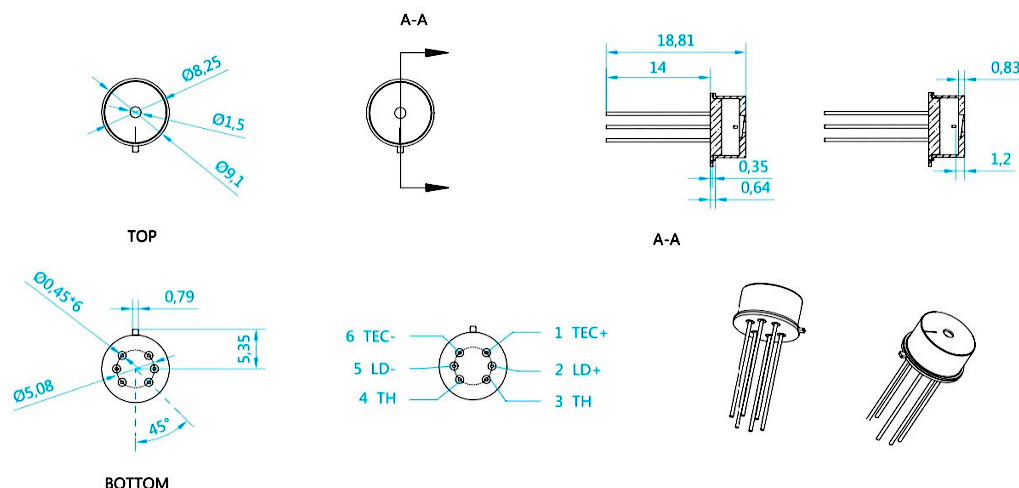


3D

Camera Analysis:



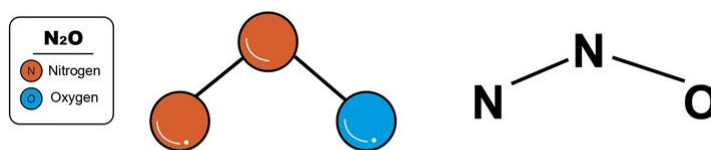
Dimensions and Pin definitions:



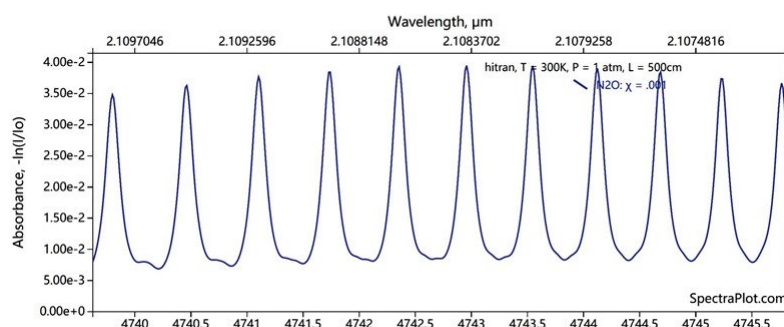
Absolute Maximum Ratings:

Item	Unit	Min	Typ	Max
Case Temperature	$^{\circ}\text{C}$	-5	25	70
Chip Temperature	$^{\circ}\text{C}$	+10	25	40
Operating Current	mA	0	100	120
Forward Voltage	V	0.8	1.2	1.8
TEC Current	A	-	-	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage (PD)	V	-	-	20

N₂O:



TDLAS: 2108nm



Ordering Info:

PL-DFB-□□□□-☆-A8▽-TO39

□□□□:Wavelength

1530: 1530nm

1653.7: 1653.7nm

2108: 2108nm

☆ :Output Power

A:5mW

B:10mW

▽:Wavelength Tolerance

1:±1nm

2:±2nm